

HD74HC4060

14-stage Binary Counter

REJ03D0650-0200 (Previous ADE-205-537) Rev.2.00 Mar 30, 2006

Description

The HD74HC4060 is a 14 stage counter, this device increments on the falling edge (negative transition) of the input clock, and all their outputs are reset to a low level by applying a logical high on their reset input. The HD74HC4060 also has two additional inputs to enable easy connection of either an RC or crystal oscillator.

Features

• High Speed Operation: t_{pd} (Clock to Q_4) = 41.5 ns typ (C_L = 50 pF)

• High Output Current: Fanout of 10 LSTTL Loads

• Wide Operating Voltage: $V_{CC} = 2$ to 6 V

• Low Input Current: 1 µA max

• Low Quiescent Supply Current: I_{CC} (static) = 4 μ A max (Ta = 25°C)

• Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74HC4060P	DILP-16 pin	PRDP0016AE-B (DP-16FV)	Р	_
HD74HC4060FPEL	SOP-16 pin (JEITA)	PRSP0016DH-B (FP-16DAV)	FP	EL (2,000 pcs/reel)

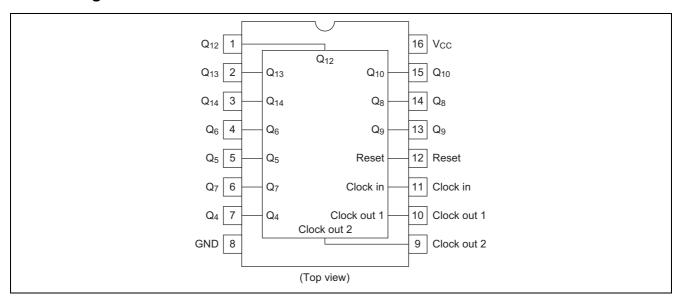
Note: Please consult the sales office for the above package availability.

Function Table

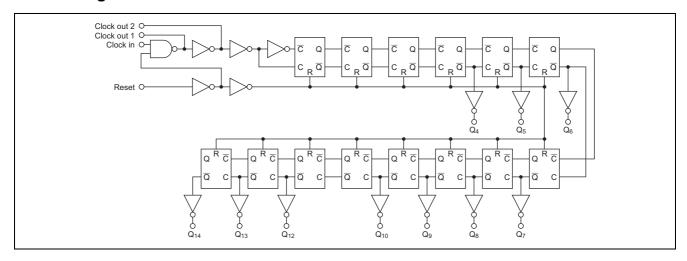
Clock in	Reset Outputs State			
	L	No change		
	L	Advance to next stage		
X	Н	All outputs are low		

X: Irrelevant

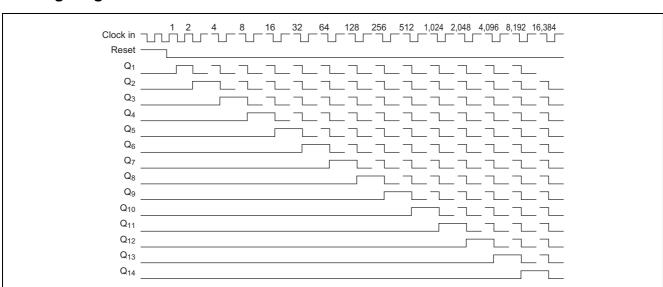
Pin Arrangement



Block Diagram



Timing Diagram



Absolute Maximum Ratings

Item	Symbol	Symbol Ratings		
Supply voltage range	V _{CC}	-0.5 to 7.0	V	
Input / Output voltage	V _{IN} , V _{OUT}	-0.5 to V _{CC} +0.5	V	
Input / Output diode current	I _{IK} , I _{OK}	±20	mA	
Output current	l _{out}	±25	mA	
V _{CC} , GND current	I _{CC} or I _{GND}	±50	mA	
Power dissipation	P _T	500	mW	
Storage temperature	Tstg	-65 to +150	°C	

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item Symbol		Ratings	Unit	Conditions
Supply voltage	V _{CC}	2 to 6	V	
Input / Output voltage	V _{IN} , V _{OUT}	0 to V _{CC}	V	
Operating temperature	Та	-40 to 85	°C	
		0 to 1000		V _{CC} = 2.0 V
Input rise / fall time*1	t_r , t_f	0 to 500	ns	$V_{CC} = 4.5 \text{ V}$
		0 to 400		V _{CC} = 6.0 V

Note: 1. This item guarantees maximum limit when one input switches.

Waveform: Refer to test circuit of switching characteristics.

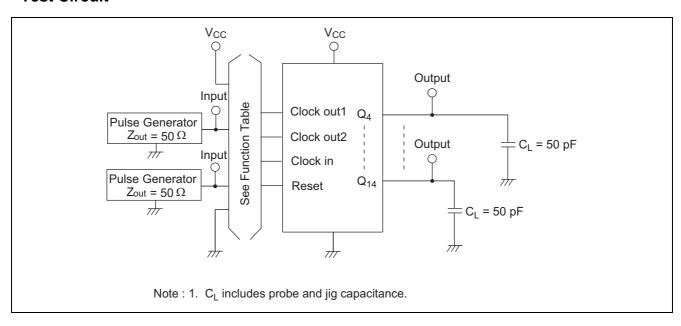
Electrical Characteristics

			Т	a = 25°	С	Ta = -40 to+85°C				
Item	Symbol	V _{cc} (V)	Min	Тур	Max	Min	Max	Unit	Test Con	ditions
Input voltage	V_{IH}	2.0	1.5	_	_	1.5	_	V		
		4.5	3.15		_	3.15	—			
		6.0	4.2	1	_	4.2	_			
	V_{IL}	2.0	_	_	0.5	_	0.5	V		
		4.5			1.35		1.35			
		6.0	_	_	1.8	_	1.8			
Output voltage	V _{OH}	2.0	1.9	2.0	_	1.9	_	V	$Vin = V_{IH} or V_{IL}$	$I_{OH} = -20 \mu A$
		4.5	4.4	4.5	_	4.4	_			
		6.0	5.9	6.0	_	5.9	_			
		4.5	4.18	_	_	4.13	_			$I_{OH} = -4 \text{ mA}$
		6.0	5.68	_	_	5.63	_			$I_{OH} = -5.2 \text{ mA}$
	V _{OL}	2.0	_	0.0	0.1	_	0.1	V	$Vin = V_{IH} or V_{IL}$	$I_{OL} = 20 \mu A$
		4.5	_	0.0	0.1	_	0.1			
		6.0	_	0.0	0.1	_	0.1			
		4.5	_	_	0.26	_	0.33			I _{OH} = 4 mA
		6.0	_	_	0.26	_	0.33			$I_{OH} = 5.2 \text{ mA}$
Input current	lin	6.0	_	_	±0.1		±1.0	μΑ	Vin = V _{CC} or GND	
Quiescent supply current	I _{CC}	6.0	_	_	4.0	_	40	μА	Vin = V _{CC} or GN	D, lout = $0 \mu A$

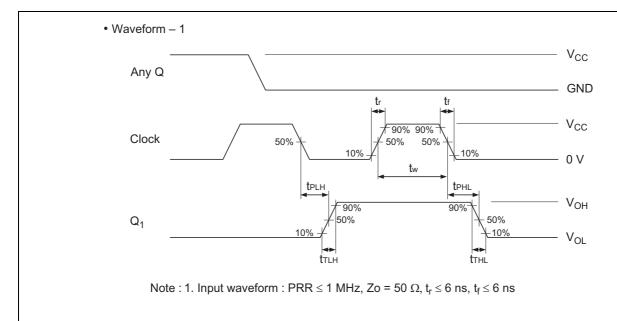
Switching Characteristics ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6 \text{ ns}$)

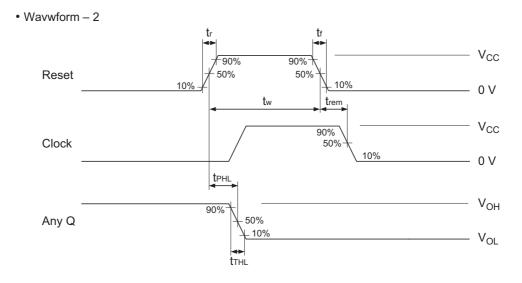
			Ta = 25°C		Ta = -40 to +85°C				
Item	Symbol	V _{cc} (V)	Min	Тур	Max	Min	Max	Unit	Test Conditions
Maximum clock	f _{max}	2.0	_	_	4	_	3	MHz	
frequency		4.5	_	_	20	_	16		
		6.0	_	_	24	_	19		
Propagation delay	t _{PLH}	2.0	_	_	300	_	375	ns	Clock to Q ₄
time		4.5	_	42	60	_	75		
		6.0	_	1	51	_	63		
	t _{PHL}	2.0	_	-	300	_	375	ns	Clock to Q ₄
		4.5	_	41	60	_	75		
		6.0	_	1	51	_	63		
	t _{PHL}	2.0	_	1	240	_	300	ns	Reset to output
		4.5	_	16	48	_	60		
		6.0	_	_	41	_	51		
Removal time	t _{rem}	2.0	100	1	_	125		ns	
		4.5	20	10	_	25	_		
		6.0	17	1	_	21			
Pulse width	t _w	2.0	80	1	_	100	_	ns	
		4.5	16	7	_	20			
		6.0	14	_	_	17	_		
Output rise/fall	t _{TLH}	2.0	_	_	75	_	95	ns	
time	t _{THL}	4.5	_	5	15	_	19		
		6.0	_	_	13	_	16		
Input capacitance	Cin	_	_	5	10	_	10	pF	

Test Circuit



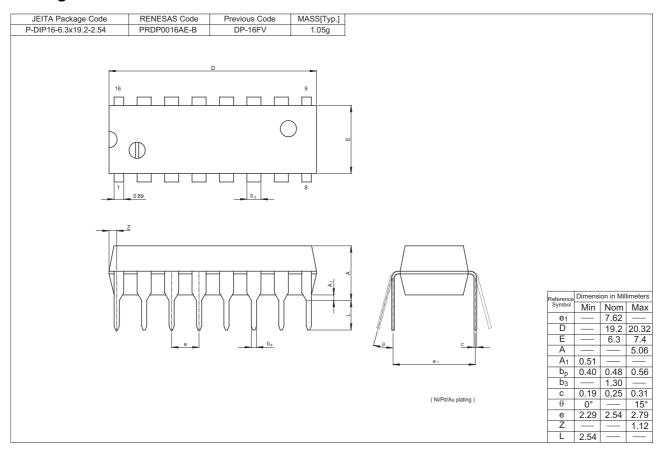
Waveforms

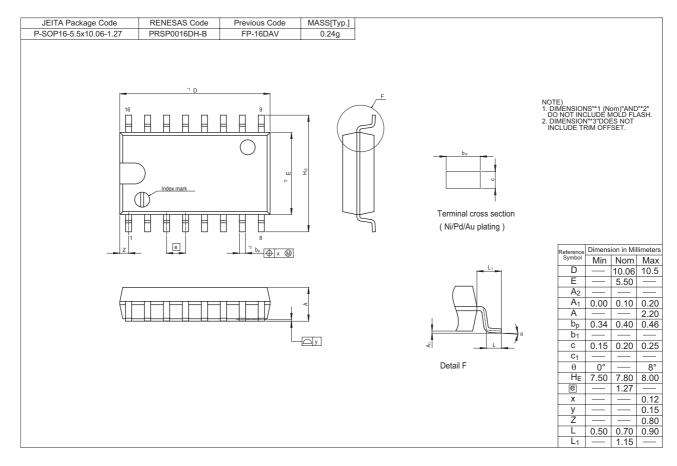




Note : 1. Input waveform : PRR \leq 1 MHz, Zo = 50 $\Omega,\,t_r \leq$ 6 ns, $t_f \leq$ 6 ns

Package Dimensions





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